FAIRCHILD SEMICONDUCTOR®

November 2012

FSA3031 — Dual High-Speed USB2.0 with Mobile High-Definition Link (MHL™)

Features

- Low On Capacitance: 4.6 pF/6.75 pF MHL/USB (Typical)
- Low Power Consumption: 30 µA Maximum
- Supports MHL Rev. 2.0
- Passes 1080 p/60 fps (3 Gbps) MHL Data Eye Diagram Mask Compliance
- MHL Data Rate: ≥4.7Gbps with Ideal Input Source
- Packaged in 12-Lead UMLP (1.8 x 1.8 mm)
- Over-Voltage Tolerance (OVT) on all USB Ports Up to 5.25 V without External Components

Applications

- Cell Phones and Digital Cameras

IMPORTANT NOTE:

For additional performance information, please contact interface@fairchildsemi.com.

Description

The FSA3031 is a bi-directional, low-power, high-speed, 3:1, dual USB2.0 and MHL switch. Configured as a double-pole, triple-throw (DP3T) switch; it is optimized for switching between dual high- or full-speed USB and Mobile High-Definition Link sources (MHL™ Rev. 2.0 specification).

The FSA3031 contains special circuitry on the switch I/O pins, for applications where the V_{CC} supply is powered off (V_{CC}=0), that allows the device to withstand an over-voltage condition. This switch is designed to minimize current consumption even when the control voltage applied to the control pins is lower than the supply voltage (V_{CC}). This feature is especially valuable to mobile applications, such as cell phones; allowing direct interface with the general-purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, digital cameras, and notebook computers.

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSA3031UMX	LX	-40 to +85°C	12-Lead, Ultrathin Molded Leadless Package (UMLP), 1.8 mm x 1.8 mm

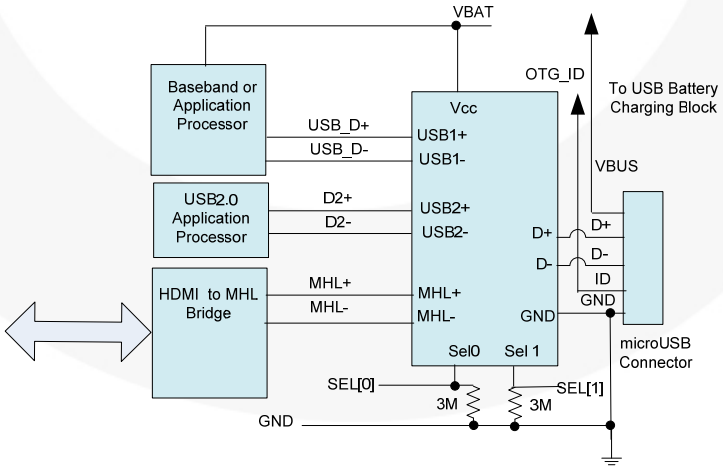

Figure 1. Typical Application

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Analog Symbol

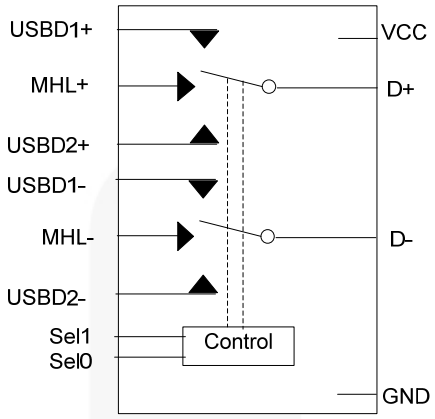


Figure 2. Analog Symbol

Table 1. Data Switch Select Truth Table

SEL1[1]	SEL0[1]	Function
0	0	D+/D- connected to USB1+/USB1-
0	1	D+/D- connected to USB2+/USB2-
1	0	D+/D- connected to MHL+/MHL
1	1	D+/D- high impedance

Note:

1. Control inputs should never be left floating or unconnected. To guarantee default switch closure to the USB position, the SEL[0:1] pins should be tied to GND with a weak pull-down resistor (3 MΩ) to minimize static current draw.

Pin Configuration

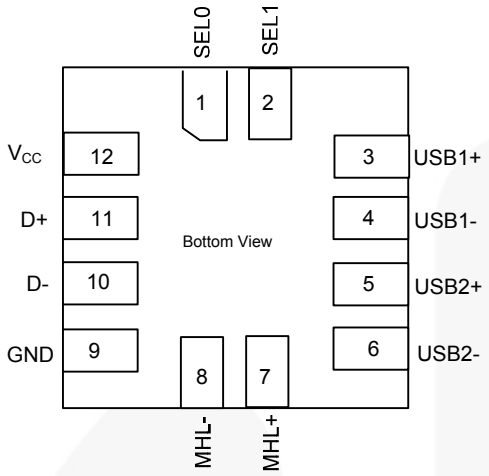


Figure 3. Pin Assignments

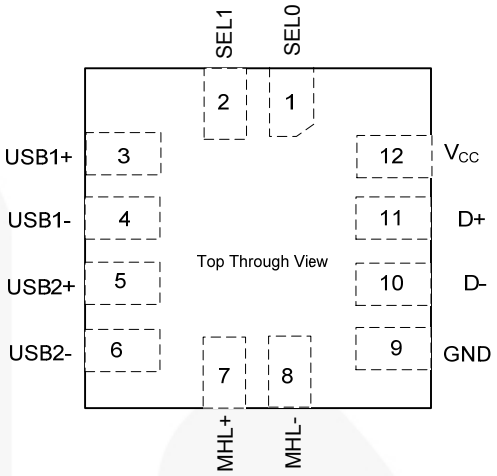


Figure 4. Top Through View

Pin Definitions

Pin#	Name	Description
1	SEL0	Data Switch Select
2	SEL1	Data Switch Select
3	USB1+	USB Differential Data (Positive) – Source 1
4	USB1-	USB Differential Data (Negative) – Source 1
5	USB2+	USB Differential Data (Positive) – Source 2
6	USB2-	USB Differential Data (Negative) – Source 2
7	MHL+	MHL Differential Data (Positive)
8	MHL-	MHL Differential Data (Negative)
9	GND	Ground
10	D-	Data Switch Output (Positive)
11	D+	Data Switch Output (Negative)
12	V_{CC}	Device Power from System

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V_{CC}	Supply Voltage		-0.5	6.0	V
V_{CNTRL}	DC Input Voltage (SEL[1:0])[2]		-0.5	V_{CC}	V
V_{SW}[3]	DC Switch I/O Voltage[2]	USB	-0.50	V_{CC}	V
		MHL	-0.50	V_{CC}	
I_{IK}	DC Input Diode Current		-50		mA
I_{OUT}	Switch DC Output Current (Continuous)	USB		60	mA
		MHL		60	mA
$I_{OUTPEAK}$	Switch DC Output Peak Current (Pulsed at 1m Duration, <10% Duty Cycle)	USB		150	mA
		MHL		150	mA
T_{STG}	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1	
ESD	Human Body Model, JEDEC: JESD22-A114	All Pins		4	kV
	IEC 61000-4-2, Level 4, for D+/D- and V_{CC} Pins[4]	Contact		8	
	IEC 61000-4-2, Level 4, for D+/D- and V_{CC} Pins[4]	Air		15	
	Charged Device Model, JESD22-C101			2	

Notes:

2. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.
3. V_{SW} refers to analog data switch paths (USB1, MHL, and USB2).
4. Testing performed in a system environment using TVS diodes.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	2.5	4.5	V
$t_{RAMP(VCC)}$	Power Supply Slew Rate	100	1000	µs/V
Θ_{JA}	Thermal Resistance		230	C°/W
V_{CNTRL}	Control Input Voltage (SEL[1:0])[5]	0	4.5	V
$V_{SW(USB)}$	Switch I/O Voltage (USB1/USB2 Switch Paths)	-0.5	3.6	V
$V_{SW(MHL)}$	Switch I/O Voltage (MHL Switch Path)	1.65	3.45	V
T_A	Operating Temperature	-40	+85	°C

Note:

5. The control inputs must be held HIGH or LOW; they must not float.

DC Electrical Characteristics

All typical values are at T_A=25°C unless otherwise specified.

Symbol	Parameter	Condition	V_{CC} (V)	T_A=- 40°C to +85°C			Unit
				Min.	Typ.	Max.	
V_{IK}	Clamp Diode Voltage	I_{IN}=-18 mA	2.5			-1.2	V
V_{IH}	Control Input Voltage, High SEL[1:0]		2.5 to 4.5	1.0			V
V_{IL}	Control Input Voltage, Low SEL[1:0]		2.5 to 4.5			0.5	V
I_{IN}	Control Input Leakage, SEL[1:0]	V_{SW}=0 to 3.6 V, V_{CNTRL}=0 to V_{CC}	4.5	-0.5		0.5	µA
$I_{OZ(MHL)}$	Off-State Leakage for Open MHL Data Paths	V_{SW}=1.65≤ MHL ≤ 3.45 V,SEL[1:0]=V_{CC}	4.5	-0.5		0.5	µA
$I_{OZ(USB)}$	Off-State Leakage for Open USB Data Paths	V_{SW}=0 ≤ USB≤ 3.6 V, SEL[1:0]=V_{CC}	4.5	-0.5		0.5	µA
$I_{CL(MHL)}$	On-State Leakage for Closed MHL Data Paths(6)	V_{SW}=1.65≤ MHL ≤ 3.45 V, SEL0=GND, SEL1=V_{CC}, Other Side of Switch Float	4.5	-0.5		0.5	µA
$I_{CL(USB)}$	On-State Leakage for Closed USB Data Paths(6)	V_{SW}=0 ≤ USB ≤ 3.6 V SEL[1:0]=GND or SEL1=GND, SEL0=V_{CC}, Other Side of Switch Float	4.5	-0.5		0.5	µA
I_{OFF}	Power-Off Leakage Current (All I/O Ports)	V_{SW}=0 V or 3.6 V, Figure 5	0	-0.5		0.5	µA
$R_{ON(USB)}$	HS Switch On Resistance (USB to D Path)	V_{SW}=0.4 V, I_{ON}=-8 mA SEL[1:0]=GND or SEL1=GND, SEL0=V_{CC}, Figure 6	2.5		3.9	6.5	Ω
$R_{ON(MHL)}$	HS Switch On Resistance (MHL to D Path)	V_{SW}=V_{CC}-1050 mV, SEL0=GND, SEL1=V_{CC}, I_{ON}=-8 mA, Figure 6	2.5		5		Ω
$\Delta R_{ON(MHL)}$	Difference in R_{ON} Between MHL Positive-Negative	V_{SW}=V_{CC}-1050 mV, SEL0=GND, SEL1=V_{CC}, I_{ON}=-8 mA, Figure 6,	2.5		0.03		Ω
$\Delta R_{ON(USB)}$	Difference in R_{ON} Between USB Positive-Negative	V_{SW}=0.4 V, I_{ON}=-8 mA, SEL[1:0]=GND or SEL1=GND, SEL0=V_{CC} Figure 6	2.5		0.22		Ω
$R_{ONF(MHL)}$	Flatness for R_{ON} MHL Path	V_{SW}=1.65 to 3.45 V, SEL0=GND, SEL1=V_{CC}, I_{ON}=-8 mA, Figure 6	2.5		1		Ω
I_{CC}	Quiescent Current	V_{CNTRL}=0 or 4.5 V, I_{OUT}=0	4.5			30	µA
I_{CCT}	Delta Increase in Quiescent Current per Control Pin	V_{CNTRL}= 1.65 V, I_{OUT}=0	4.5			18	µA
		V_{CNTRL}= 2.5 V, I_{OUT}=0	4.5			10	

Note:

6. For this test, the data switch is closed with the respective switch pin floating.

AC Electrical Characteristics

All typical values are for V_{CC}=3.3 V and T_A=25°C unless otherwise specified.

Symbol	Parameter	Condition	V_{CC} (V)	T_A=- 40°C to +85°C			Unit
				Min.	Typ.	Max.	
t_{ONUSB}	USB Turn-On Time, SEL[1:0] to Output	R_L=50 Ω, C_L=5 pF, $V_{SW(USB)}$=0.8 V, $V_{SW(MHL)}$=3.3 V, Figure 7, Figure 8	2.5 to 3.6		445	600	ns
t_{OFFUSB}	USB Turn-Off Time, SEL[1:0] to Output	R_L=50 Ω, C_L=5 pF, $V_{SW(USB)}$=0.8 V, $V_{SW(MHL)}$=3.3 V, Figure 7, Figure 8	2.5 to 3.6		445	600	ns
t_{ONMHL}	MHL Turn-On Time, SEL[1:0] to Output	R_L=50 Ω, C_L=5 pF, $V_{SW(USB)}$=0.8 V, $V_{SW(MHL)}$=3.3 V, Figure 7, Figure 8	2.5 to 3.6		445	600	ns
t_{OFFMHL}	MHL Turn-Off Time, SEL[1:0] to Output	R_L=50 Ω, C_L=5 pF, $V_{SW(USB)}$=0.8 V, $V_{SW(MHL)}$=3.3 V, Figure 7, Figure 8	2.5 to 3.6		445	600	ns
t_{PD}	Propagation Delay(7)	C_L=5 pF, R_L=50 Ω, Figure 7, Figure 9	2.5 to 3.6		0.25		ns
t_{BBM}	Break-Before-Make Time(7)	R_L=50 Ω, C_L=5 pF, V_{ID}=V_{MHL}=3.3 V, V_{USB}=0.8 V, Figure 11	2.5 to 3.6		85		ns
$O_{IRR(MHL)}$	Off Isolation(7)	V_S=1 V_{pk-pk}, R_L=50 Ω, f=240 MHz, Figure 12	2.5 to 3.6		-41		dB
$O_{IRR(USB)}$		V_S=400 mV_{pk-pk}, R_L=50 Ω, f=240 MHz, Figure 12	2.5 to 3.6		-36		dB
$Xtalk_{MHL}$	Non-Adjacent Channel(7) Crosstalk	V_S=1 V_{pk-pk}, R_L=50 Ω, f=240 MHz, Figure 13	2.5 to 3.6		-41		dB
$Xtalk_{USB}$		V_S=400 mV_{pk-pk}, R_L=50 Ω, f=240 MHz, Figure 13	2.5 to 3.6		-37		dB
BW	Differential -3db Bandwidth(7)	V_{IN}=1 V_{pk-pk}, MHL Path, Common Mode Voltage = V_{CC} – 1.1 V, R_L=50 Ω, C_L=0 pF, Figure 14	2.5 to 3.6		1.87		GHz
		V_{IN}=400 mV_{pk-pk}, USB Path, Common Mode Voltage = 0.2 V, R_L=50 Ω, C_L=0 pF, Figure 14			1.47		

Note:

7. Guaranteed by characterization.

USB High-Speed AC Electrical Characteristics

Typical values are at T_A= -40ºC to +85ºC.

Symbol	Parameter	Condition	V_{CC}(V)	Typ.	Unit
$t_{SK(P)}$	Skew of Opposite Transitions of the Same Output[8]	C_L=5 pF, R_L=50 Ω, Figure 9	3.0 to 3.6	7	ps
t_J	Total Jitter[8]	R_L=50 Ω, C_L=5 pF, t_R=t_F=500 ps (10-90%) at 480 Mbps, PN7	3.0 to 3.6	18	ps

Note:
8. Guaranteed by characterization.

MHL AC Electrical Characteristics

Typical values are at T_A= -40ºC to +85ºC.

Symbol	Parameter	Condition	V_{CC}(V)	Typ.	Unit
$t_{SK(P)}$	Skew of Opposite Transitions of the Same Output[9]	R_{PU}=50 Ω to V_{CC}, C_L=0 pF	3.0 to 3.6	3	ps
t_J	Total Jitter[9]	f=2.25 Gbps, PN7, R_{PU}=50 Ω to V_{CC}, C_L=0 pF	3.0 to 3.6	23	ps

Note:
9. Guaranteed by characterization.

Capacitance

Typical values are at T_A= -40ºC to +85ºC.

Symbol	Parameter	Condition	Typ.	Max.	Unit
C_{IN}	Control Pin Input Capacitance[10]	V_{CC}=0 V, f=1 MHz	2.5		pF
$C_{ON(USB)}$	USB Path On Capacitance[10]	V_{CC}=3.3 V, f=240 MHz, Figure 15	6.75		pF
$C_{OFF(USB)}$	USB Path Off Capacitance[10]	V_{CC}=3.3 V, f=240 MHz, Figure 13	2.5		pF
$C_{ON(MHL)}$	MHL Path On Capacitance[10]	V_{CC}=3.3 V, f=240 MHz, Figure 15	4.6		pF
$C_{OFF(MHL)}$	MHL Path Off Capacitance[10]	V_{CC}=3.3 V, f=240 MHz, Figure 13	2.5		pF

Note:
10. Guaranteed by characterization.

Test Diagrams

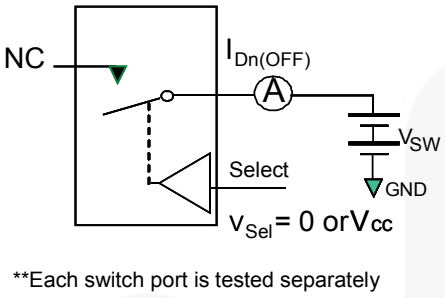


Figure 5. Off Leakage

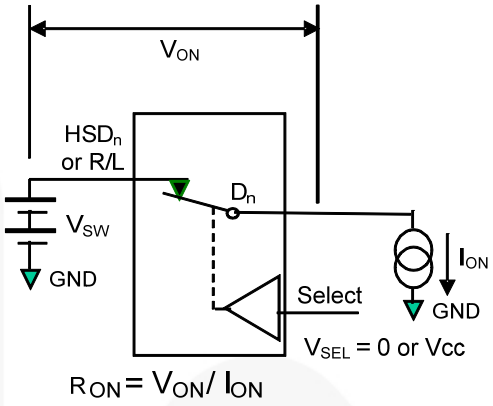


Figure 6. On Resistance

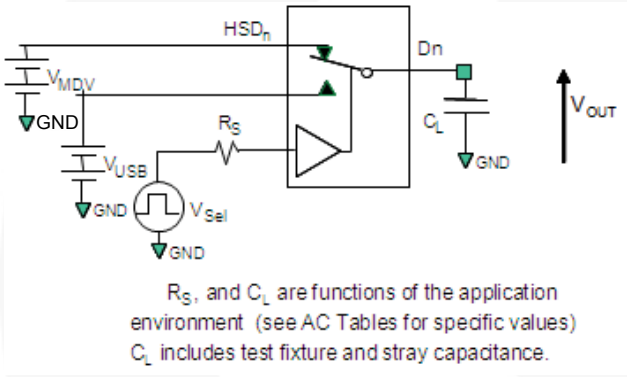


Figure 7. AC Test Circuit Load

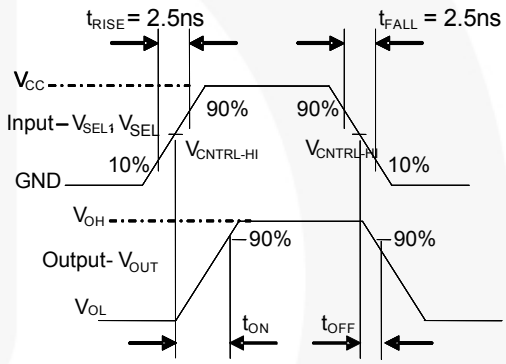


Figure 8. Turn-On / Turn-Off Waveforms

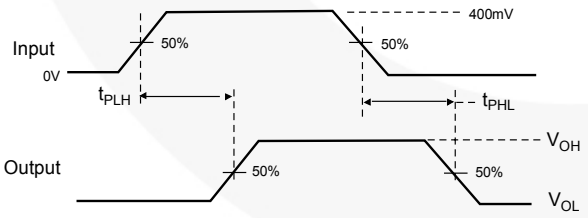


Figure 9. Propagation Delay ($t_R t_F$ – 500ps)

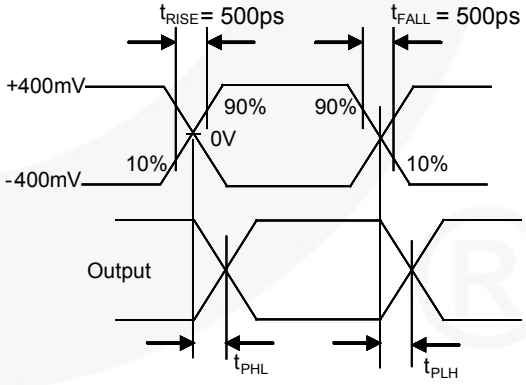
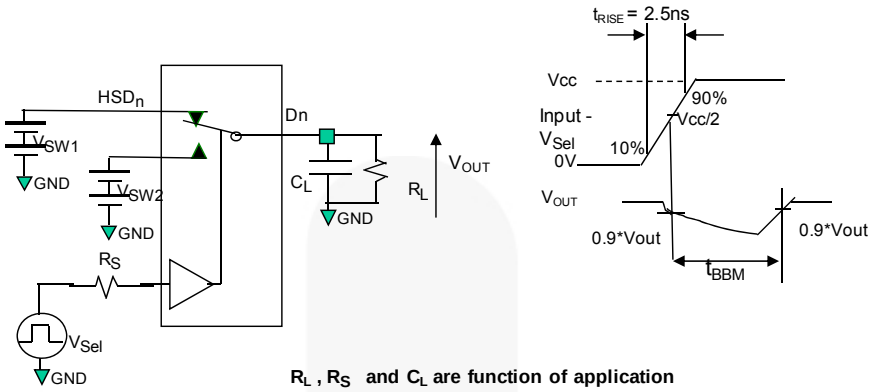


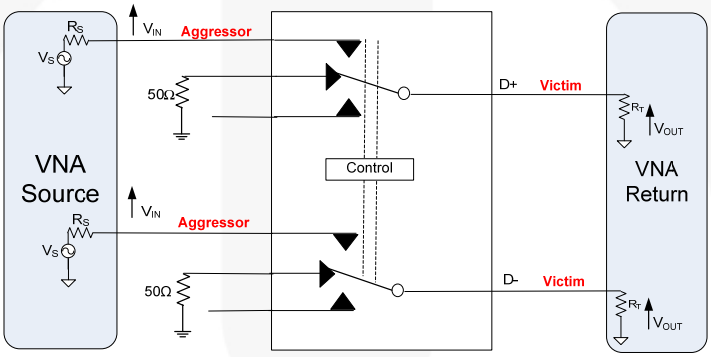
Figure 10. Intra-Pair Skew Test $t_{SK(P)}$

Test Diagrams



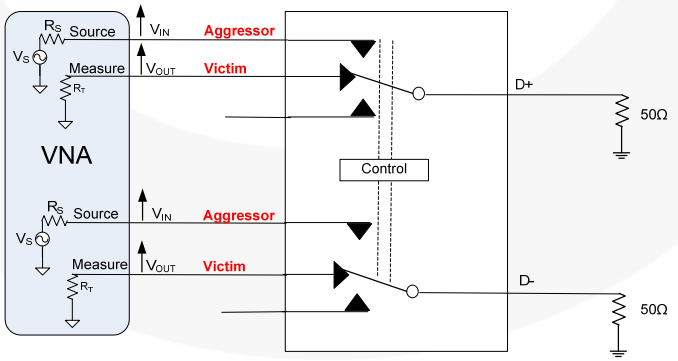
R_L , R_S and C_L are function of application environment (see AC Tables for specific values)
C_L includes test fixture and stray capacitance

Figure 11. Break-Before-Make Interval Timing



V_S, R_S and R_T are functions of the application environment (see AC/DC Tables for values).
Off Isolation = 20 Log (V_{OUT} - V_{IN})

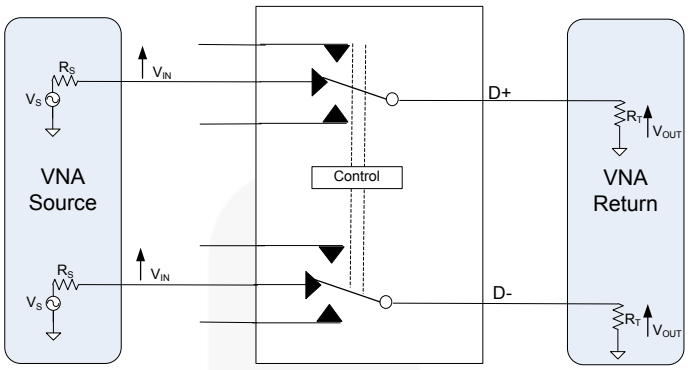
Figure 12. Channel Off Isolation (SDD21)



VS, RS and RT are functions of the application environment (see AC/DC Tables for values).
Off Isolation = 20 Log (VOUT - VIN)

Figure 13. Non-Adjacent Channel-to-Channel Crosstalk (SDD21)

Test Diagrams



V_S, R_S and R_T are functions of the application environment (see AC/DC Tables for values).

Figure 14. Insertion Loss (SDD21)

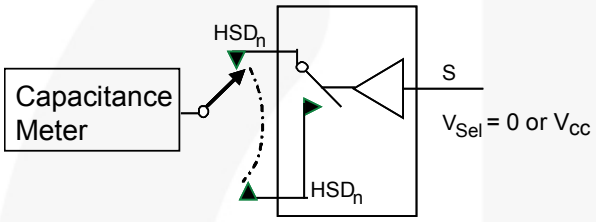


Figure 15. Channel Off Capacitance

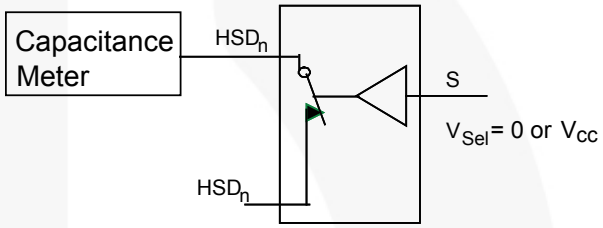


Figure 16. Channel On Capacitance

Note:

11. HSD_n refers to the high-speed data USB or MHL paths.

Functional Description

Insertion Loss

One of the key advantages of using the FSA3031 in mobile digital video applications is the small amount of insertion loss experienced by the received signal as it passes through the switch.

This results in minimal degradation of the received eye. One of the ways to measure the quality of the high data rate channels is using balanced ports and four-port differential S-parameter analysis, particularly SDD21.

Bandwidth is measured using the S-parameter SDD21 methodology. Figure 17 exhibits the 1.87 GHz (-3 db) BW of the MHL path, while Figure 18 exhibits the 1.47 GHz (-3 db) BW of the USB paths.

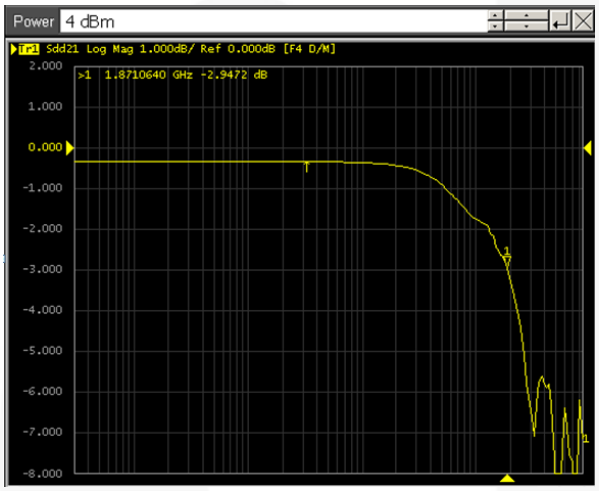


Figure 17. MHL Path SDD21 Insertion Loss Curve

Figure 18. USB Path SDD21 Insertion Loss Curve

Typical Application

Figure 19 shows utilizing the VBAT connection from the micro-USB connector. The 3M resistors are used to ensure, for manufacturing test via the micro-USB connector, that the FSA3031 configures for connectivity to the baseband or application processor.

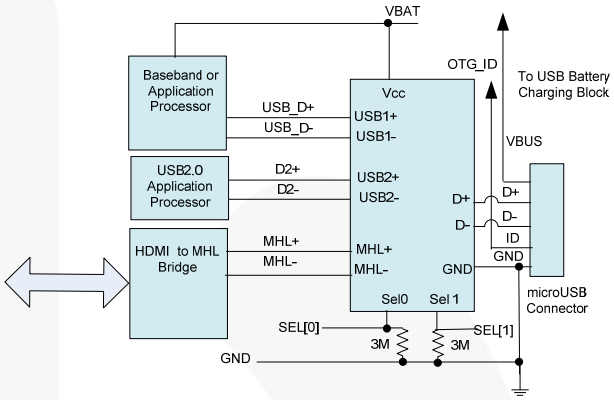
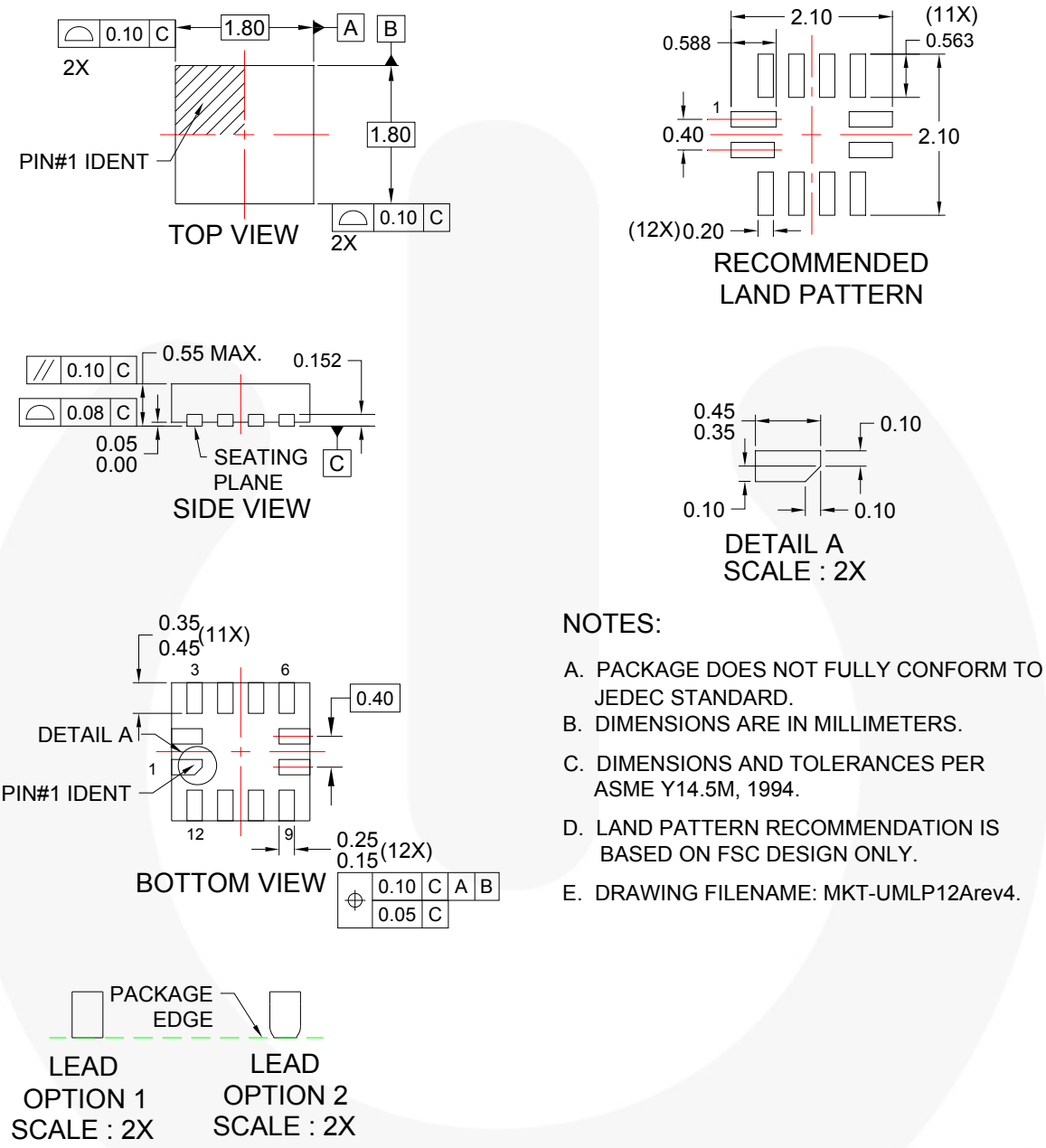


Figure 19. Typical Application

Physical Dimensions



NOTES:

A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC STANDARD.
B. DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
D. LAND PATTERN RECOMMENDATION IS BASED ON FSC DESIGN ONLY.
E. DRAWING FILENAME: MKT-UMLP12Arev4.

Figure 20. 12-Lead, Ultrathin Molded Leadless Package (UMLP)

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Current Transfer Logic™
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Dual Cool™
EcoSPARK®
EfficientMax™
ESBC™
F®
Fairchild®
Fairchild Semiconductor®
FACT Quiet Series™
FACT®
FAST®
FastvCore™
FETBench™
FlashWriter®*
FPS™
F-PFS™
FRFET®
Global Power Resource℠
GreenBridge™
Green FPS™
Green FPS™ e-Series™
Gmax™
GTO™
IntelliMAX™
ISOPLANAR™
Making Small Speakers Sound Louder and Better™
MegaBuck™
MICROCOUPLER™
MicroFET™
MicroPak™
MicroPak2™
MillerDrive™
MotionMax™
mWSaver™
OptoHiT™
OPTOLOGIC®
OPTOPLANAR®
PowerTrench®
PowerXS™
Programmable Active Droop™
QFET®
QS™
Quiet Series™
RapidConfigure™
™
Saving our world, 1mW/W/kW at a time™
SignalWise™
SmartMax™
SMART START™
Solutions for Your Success™
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STEALTH™
SuperFET®
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SupreMOS®
SyncFET™
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Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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Rev. I62

Modified Recommended Vcc min to 2.5V Deleted Sdd21 BW plots Updated all test conditions to new values based on 2.5V min Split out Abs Max specs for each switch path
Tech doc edit/format pass, updated tm page
Changed MHL Data Rate to 3.6Gbps and MHL BW to 1.8GHz (BC)
Added Theta JA (A Lam)
Changed HBM to 4KV and CDM to 2KV per ESD results. Added Common Mode Voltage Conditions to the BW parameter. Updated BW, OIRR & Xtalk measurement diagrams. Added MHL Eye Diagram Scope Shots. Changed MHL BW to 1.87GHz (typ) based on bench evaluation Changed USB BW to 1.47GHz (typ) based on bench evaluation Changed OIRR (USB) to -36db (typ), based on bench evaluation Changed OIRR (MHL) to -41db (typ) based on bench evaluation Changed Xtalk (USB) to -37db (typ) based on bench evaluation Changed Xtalk (MHL) to -41db (typ) based on bench evaluation Changed delta Ron (USB) from 0.18 to 0.22ohms based on bench evaluation. Changed CIN (sel pins) from 1.5pF to 2.5pF based on bench evaluation. Changed CON (USB) from 5pF (typ) to 6.75pF (typ) and removed the max. Changed CON (MHL) from 4.2pF (typ) to 4.6pF (typ). Changed TBBM to 85ns (typ) based on bench evaluation. Added ICL Condition, “other side of switch float”.
Updated the UMLP12A drawing from rev 3 to rev 4 Updated the TM page to i61 Updated all typed figure # to styles & references to them to digital cross refs Updated rev, date, standard stuff; removed Advance header Added top mark
Removed eye diagrams
Add that FSA3031 meet the 1080P/60f, and remove the min bandwidth 1.8GHZ , and put the typcial value, "features" bullet 1 change Low On Capacitance to 4.6/6.75pF
Updated Tskew to 7ns (USB), Tj to 23ps (MHL) and Tj to 18ps(USB) based on Char data (Alvan) Added 4.7Gbps bullet, with an ideal source. Updated skew and jitter typ specs.
Updated the UMLP12A drawing (new Rev 4), updated the TM page to i62
Updated VIH/VIL min Vcc condition to 2.5V (to match FSA3200)
updated to MHL Rev. 2.0, added non breaking space before the UNOM to comply with IEEE Standards.,

Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
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- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
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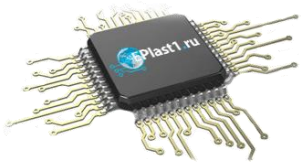
- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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